Infrared Emitter (850 nm) Version 1.3

SFH 4855



Features:

- Wavelength 850nm
- Hermetically sealed package
- · Short switching times
- · Spectral match with silicon photodetectors

Applications

- Photointerrupters
- · Sensor technology
- · Light curtains

Notes

Depending on the mode of operation, these devices emit highly concentrated non visible infrared light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1 and IEC 62471.

Ordering Information

Туре:	Radiant Intensity	Ordering Code
	I _e [mW/sr]	
	I _F = 100 mA, t _p = 20 ms	
SFH 4855	110 (≥ 40)	Q65111A6128
SFH 4855-VAW	63 200	Q65111A9675

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Note: Measured at a solid angle of $\Omega = 0.01 \text{ sr}$



Maximum Ratings $(T_A = 25 \, ^{\circ}C)$

Parameter	Symbol	Values	Unit
Operation and storage temperature range	$T_{op}; T_{stg}$	-40 125	°C
Reverse voltage	V_R	5	V
Forward current	I _F	100	mA
Surge current $(t_p \le 200 \ \mu s, \ D = 0)$	I _{FSM}	1	Α
Power consumption	P _{tot}	200	mW
Thermal resistance junction - ambient	R_{thJA}	500	K/W
Thermal resistance junction - case	R_{thJC}	350	K/W
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	V _{ESD}	2	kV

Characteristics $(T_A = 25 \, ^{\circ}C)$

Parameter		Symbol	Values	Unit
Peak wavelength (I _F = 100 mA, t _p = 20 ms)	(typ)	λ_{peak}	860	nm
Centroid wavelength ($I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$)	(typ)	$\lambda_{\text{centroid}}$	850	nm
Spectral bandwidth at 50% of I_{max} ($I_F = 100 \text{ mA}$, $t_p = 20 \text{ ms}$)	(typ)	Δλ	30	nm
Half angle	(typ)	φ	± 8	0
Dimensions of active chip area	(typ)	LxW	0.3 x 0.3	mm x mm
Distance chip surface to lens top	(min max)	Н	4 4.8	mm
Rise and fall time of I_e (10% and 90% of $I_{e\;max}$) ($I_F=100\;mA,\;R_L=50\;\Omega)$	(typ)	t _r , t _f	12	ns
Forward voltage $(I_F = 100 \text{ mA}, t_p = 20 \text{ ms})$	(typ (max))	V _F	1.7 (≤ 2)	V
Forward voltage $(I_F = 1A, t_p = 100 \mu s)$	(typ (max))	V_{F}	3.6 (≤ 4.6)	V
Reverse current (V _R = 5 V)		I _R	not designed for reverse operation	μΑ
Total radiant flux $(I_F=100 \text{ mA}, t_p=20 \text{ ms})$	(typ)	Фе	35	mW



Parameter		Symbol	Values	Unit
Temperature coefficient of I_e or Φ_e ($I_F = 100 \text{ mA}$, $t_p = 20 \text{ ms}$)	(typ)	TC _I	-0.3	% / K
Temperature coefficient of V_F ($I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$)	(typ)	TC _V	-0.6	mV / K
Temperature coefficient of wavelength $(I_F = 100 \text{ mA}, t_D = 20 \text{ ms})$	(typ)	TC_λ	0.3	nm / K

Grouping ($T_A = 25 \, ^{\circ}C$)

Group	Min Radiant Intensity	Max Radiant Intensity	Typ Radiant Intensity
	I _F = 100 mA, t _p = 20 ms	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$I_F = 1 A, t_p = 100 \mu s$
	I _{e, min} [mW / sr]	I _{e, max} [mW / sr]	I _{e, typ} [mW / sr]
SFH 4855-U	40	80	250
SFH 4855-V	63	125	400
SFH 4855-AW	100	200	630
SFH 4855-BW	160	320	980

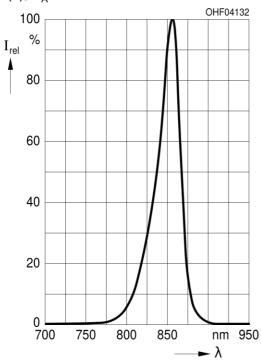
Note: measured at a solid angle of $\Omega = 0.01$ sr

Only one group in one packing unit (variation lower 2:1).



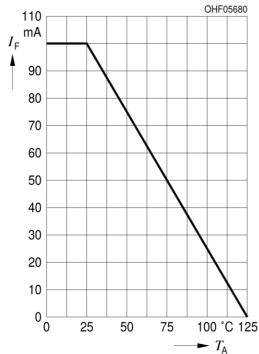
Relative Spectral Emission 1) page 9

 $I_{rel} = f(\lambda), T_A = 25^{\circ}C$



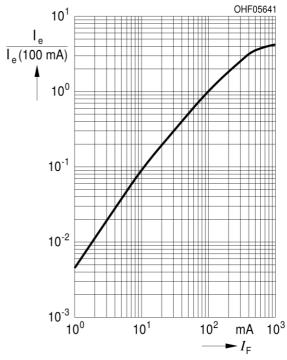
Max. Permissible Forward Current

 $I_{F, max} = f(T_A), R_{thJA} = 500 \text{ K} / \text{W}$



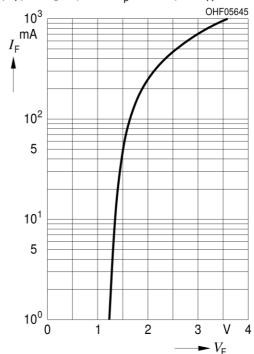
Radiant Intensity 1) page 9

 I_e / I_e (100 mA) = $f(I_F)$, single pulse, t_p = 100 μ s, T_A = 25°C



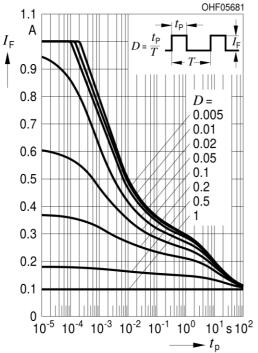
Forward Current 1) page 9

 $I_F = f(V_F)$, single pulse, $t_p = 100 \mu s$, $T_A = 25^{\circ} C$



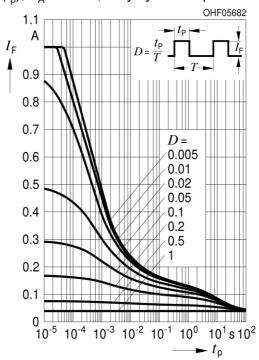
Permissible Pulse Handling Capability

 $I_F = f(t_p)$, $T_A = 25$ °C, duty cycle D = parameter



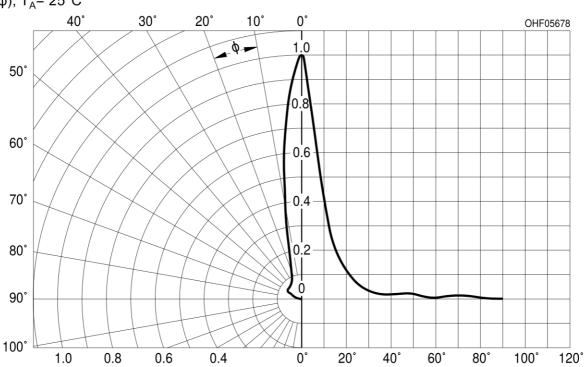
Permissible Pulse Handling Capability

 $I_F = f(t_p)$, $T_A = 85$ °C, duty cycle D = parameter

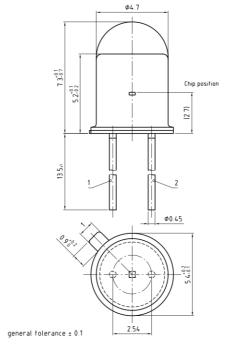


Radiation Characteristics 1) page 9

 $I_{rel} = f(\phi), T_A = 25^{\circ}C$



Package Outline



C63062-A4266-A1-02

Dimensions in mm.

Pinning

Pin	Description
1	Cathode
2	Anode

Package

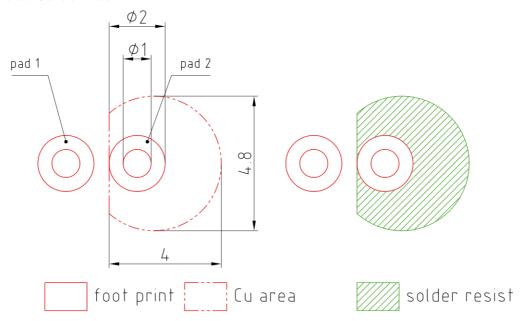
Metal Can (TO-18), hermetically sealed

Approximate Weight:

0.4 g



Recommended Solder Pad



E062.3010.188-01

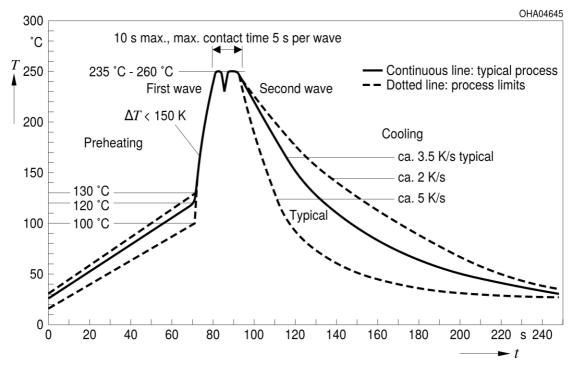
Dimensions in mm.

Note:

pad 1: cathode

TTW Soldering

IEC-61760-1 TTW





Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

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- **) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.



Glossary

Typical Values: Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.



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